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ON Semiconductor®

August 2017

ISL9K460P3 8 A, 600 V, STEALTH™ II Diode

Features

- Stealth Recovery $t_{rr} = 17 \text{ ns}$ (@ $I_F = 4 \text{ A}$)
- Max Forward Voltage, $V_F = 2.4 \text{ V}$ (@ $T_C = 25^\circ\text{C}$)
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- RoHS Compliant

Applications

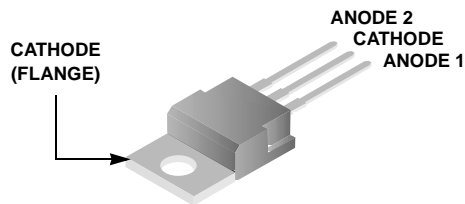
- SMPS FWD
- Hard Switched PFC Boost Diode
- UPS Free Wheeling Diode
- Motor Drive FWD
- Snubber Diode

Description

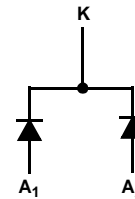
The ISL9K460P3 is a STEALTH™ dual diode optimized for low loss performance in high frequency hard switched applications. The STEALTH™ family exhibits low reverse recovery current (I_{rr}) and exceptionally soft recovery under typical operating conditions. This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low I_{rr} and short t_a phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the STEALTH™ diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

Package

JEDEC TO-220AB



Symbol



Device Maximum Ratings (per leg) $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Rating	Unit
V_{RRM}	Peak Repetitive Reverse Voltage	600	V
V_{RWM}	Working Peak Reverse Voltage	600	V
V_R	DC Blocking Voltage	600	V
$I_{F(AV)}$	Average Rectified Forward Current ($T_C = 155^\circ\text{C}$)	4	A
	Total Device Current (Both Legs)	8	A
I_{FRM}	Repetitive Peak Surge Current (20kHz Square Wave)	8	A
I_{FSM}	Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60Hz)	50	A
P_D	Power Dissipation	58	W
E_{AVL}	Avalanche Energy (0.5A, 80mH)	10	mJ
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to 175	$^\circ\text{C}$
T_L T_{PKG}	Maximum Temperature for Soldering	300	$^\circ\text{C}$
	Leads at 0.063in (1.6mm) from Case for 10s Package Body for 10s, See Techbrief TB334	260	$^\circ\text{C}$

CAUTION: Stresses above those listed in "Device Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

ISL9K460P3 — STEALTH™ Dual Diode

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
ISL9K460P3	K460P3	TO-220	Tube	N/A	N/A	50

Electrical Characteristics (per leg) $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
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Off State Characteristics

I_R	Instantaneous Reverse Current	$V_R = 600\text{ V}$	$T_C = 25^\circ\text{C}$	-	-	100	μA
			$T_C = 125^\circ\text{C}$	-	-	1.0	mA

On State Characteristics

V_F	Instantaneous Forward Voltage	$I_F = 4\text{ A}$	$T_C = 25^\circ\text{C}$	-	2.0	2.4	V
			$T_C = 125^\circ\text{C}$	-	1.6	2.0	V

Dynamic Characteristics

C_J	Junction Capacitance	$V_R = 10\text{ V}, I_F = 0\text{ A}$	-	19	-	pF
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Switching Characteristics

t_{rr}	Reverse Recovery Time	$I_F = 1\text{ A}, di_F/dt = 100\text{ A}/\mu\text{s}, V_R = 30\text{ V}$	-	17	20	ns
			$I_F = 4\text{ A}, di_F/dt = 100\text{ A}/\mu\text{s}, V_R = 30\text{ V}$	-	19	22
t_{rr}	Reverse Recovery Time	$I_F = 4\text{ A},$	-	17	-	ns
I_{rr}	Reverse Recovery Current	$di_F/dt = 200\text{ A}/\mu\text{s}, V_R = 390\text{ V},$	-	2.6	-	A
Q_{rr}	Reverse Recovery Charge	$T_C = 25^\circ\text{C}$	-	22	-	nC
t_{rr}	Reverse Recovery Time	$I_F = 4\text{ A},$	-	77	-	ns
S	Softness Factor (t_b/t_a)	$di_F/dt = 200\text{ A}/\mu\text{s},$	-	4.2	-	
I_{rr}	Reverse Recovery Current	$V_R = 390\text{ V},$	-	2.8	-	A
Q_{rr}	Reverse Recovery Charge	$T_C = 125^\circ\text{C}$	-	100	-	nC
t_{rr}	Reverse Recovery Time	$I_F = 4\text{ A},$	-	54	-	ns
S	Softness Factor (t_b/t_a)	$di_F/dt = 400\text{ A}/\mu\text{s},$	-	3.5	-	
I_{rr}	Reverse Recovery Current	$V_R = 390\text{ V},$	-	4.3	-	A
Q_{rr}	Reverse Recovery Charge	$T_C = 125^\circ\text{C}$	-	110	-	nC
di_M/dt	Maximum di/dt during t_b		-	500	-	$\text{A}/\mu\text{s}$

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction to Case		-	-	2.6	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient	TO-220	-	-	62	$^\circ\text{C}/\text{W}$

Typical Performance Curves

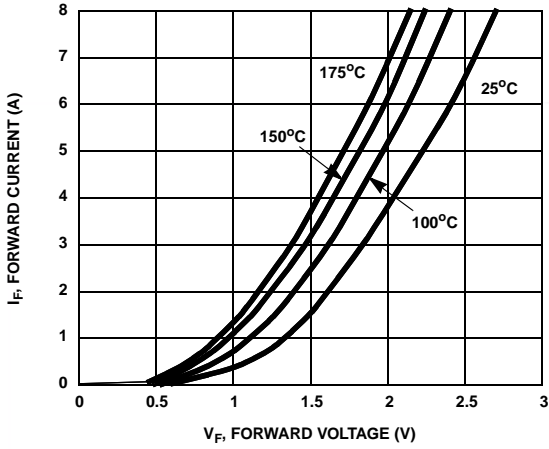


Figure 1. Forward Current vs Forward Voltage

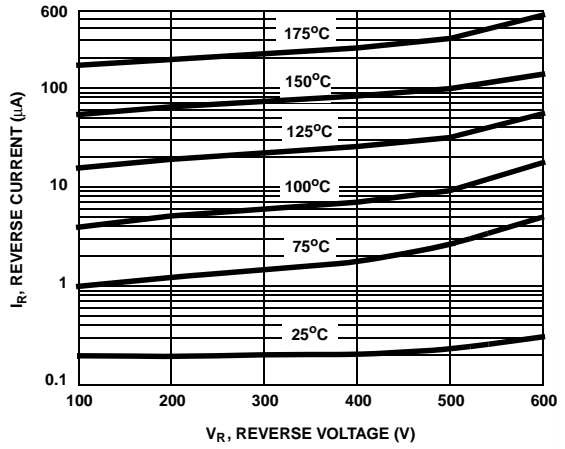


Figure 2. Reverse Current vs Reverse Voltage

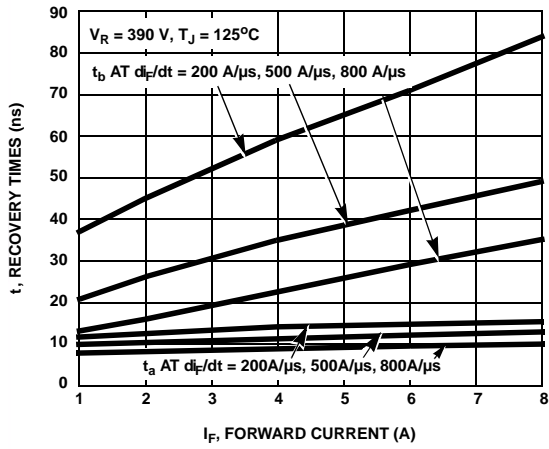


Figure 3. t_a and t_b Curves vs Forward Current

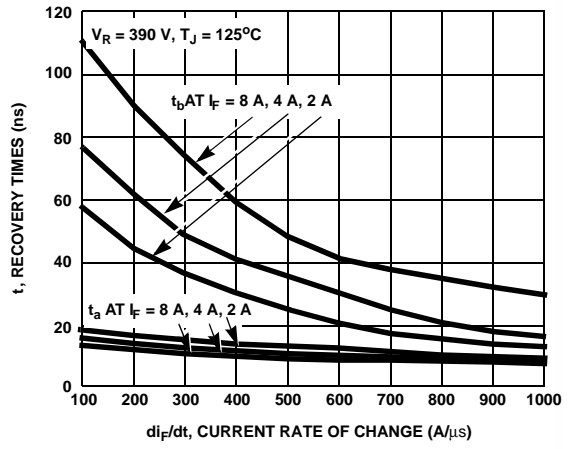


Figure 4. t_a and t_b Curves vs di_F/dt

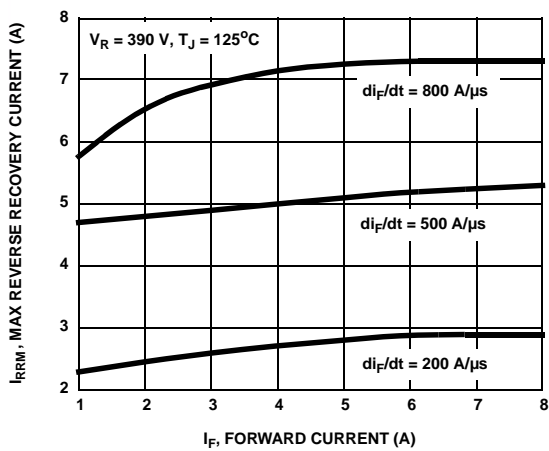


Figure 5. Maximum Reverse Recovery Current vs Forward Current

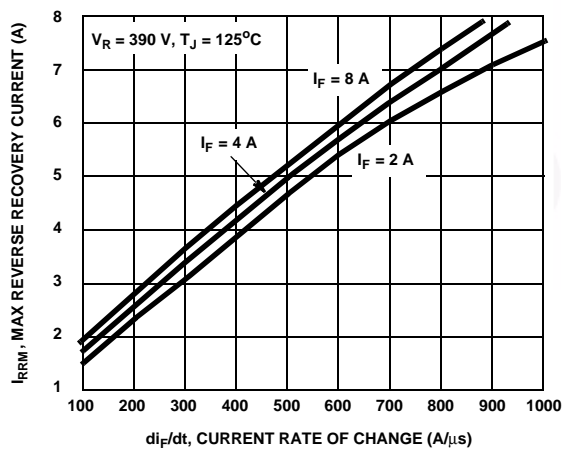


Figure 6. Maximum Reverse Recovery Current vs di_F/dt

Typical Performance Curves (Continued)

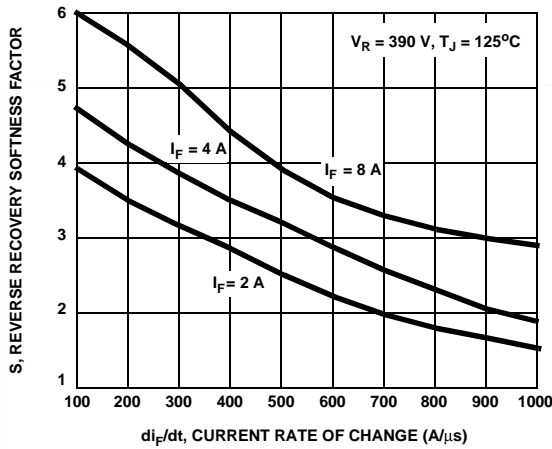


Figure 7. Reverse Recovery Softness Factor vs di_F/dt

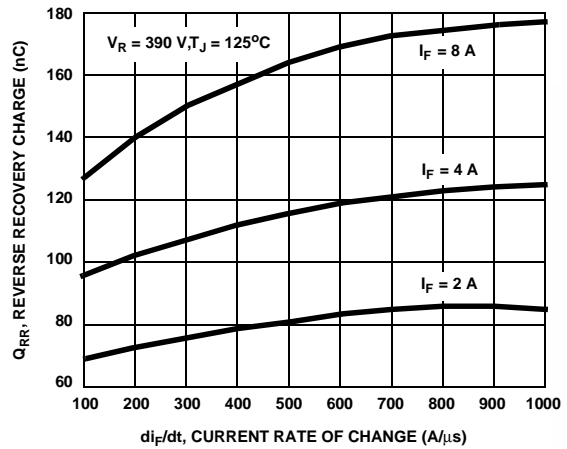


Figure 8. Reverse Recovery Charge vs di_F/dt

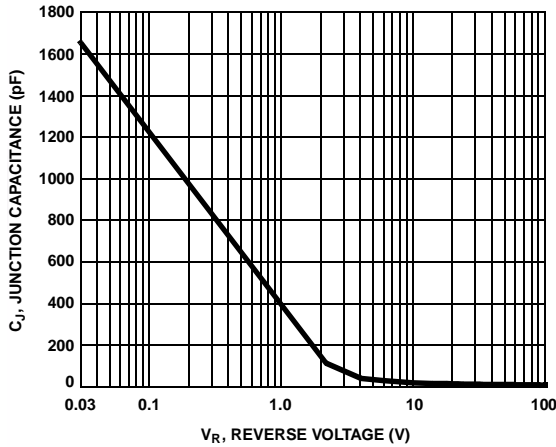


Figure 9. Junction Capacitance vs Reverse Voltage

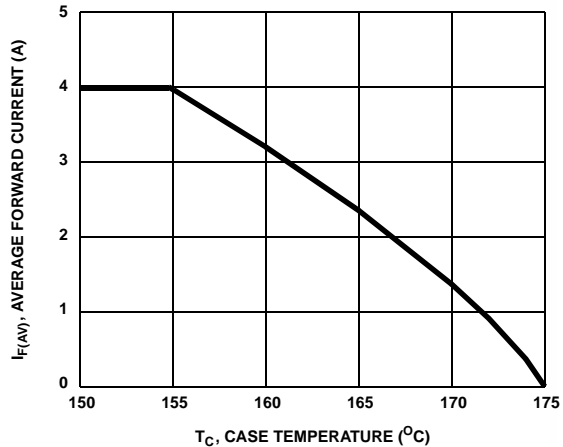


Figure 10. DC Current Derating Curve

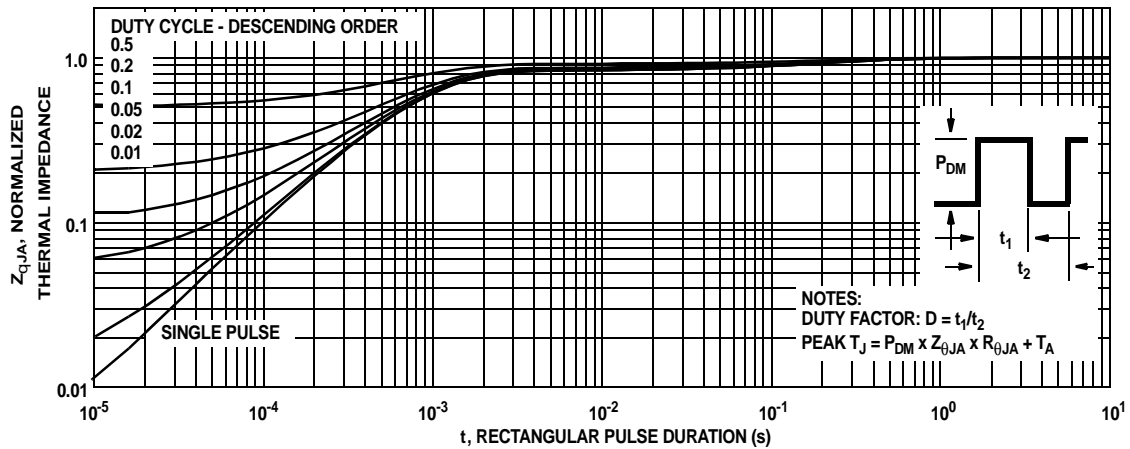


Figure 11. Normalized Maximum Transient Thermal Impedance

Test Circuit and Waveforms

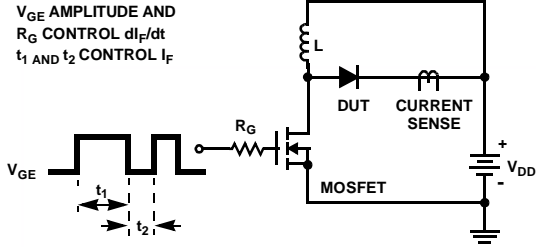


Figure 12. t_{rr} Test Circuit

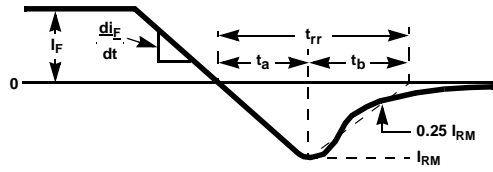


Figure 13. t_{rr} Waveforms and Definitions

$I = 0.5A$
 $L = 80mH$
 $R < 0.1\Omega$
 $V_{DD} = 200V$
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$
 $Q_1 = IGBT (BV_{CES} > DUT V_{R(AVL)})$

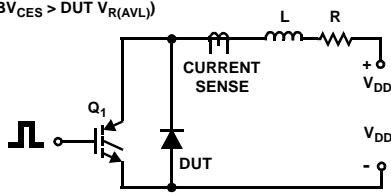


Figure 14. Avalanche Energy Test Circuit

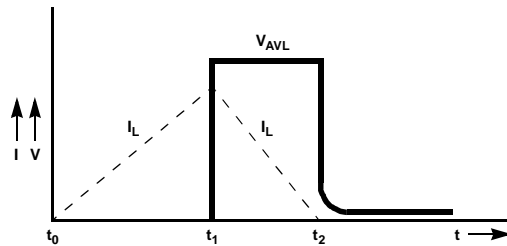


Figure 15. Avalanche Current and Voltage Waveforms

Mechanical Dimensions

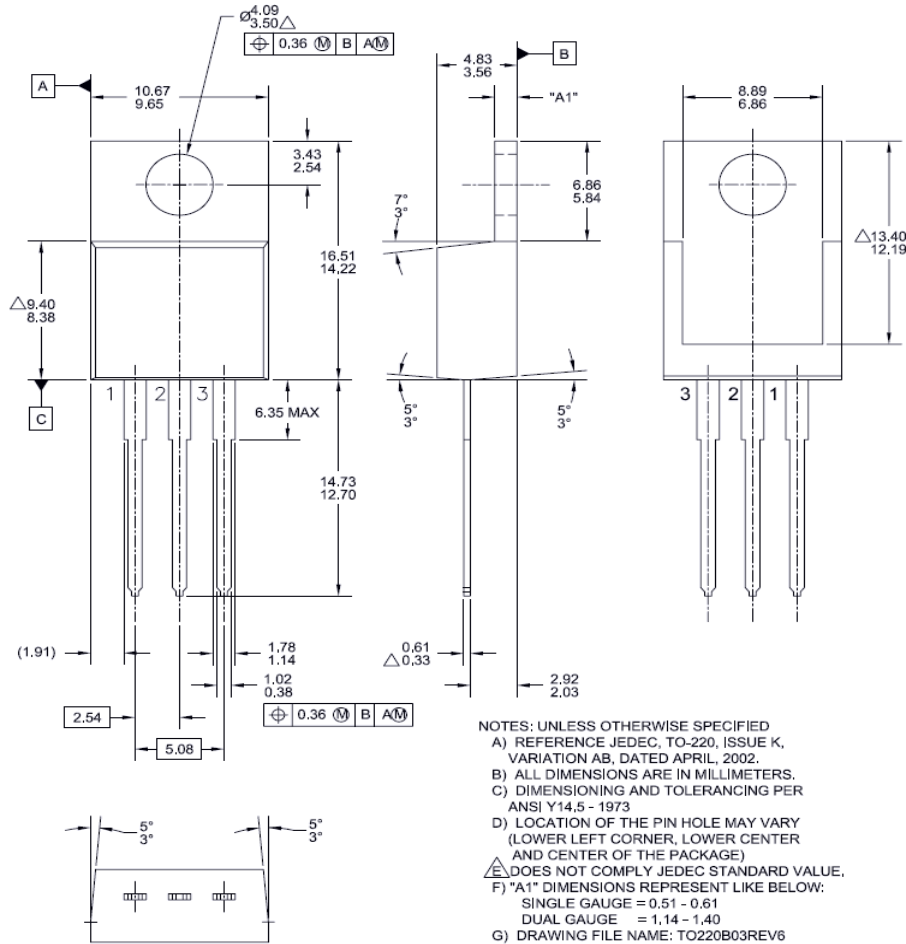


Figure 16. TO-220 3L - TO-220, MOLDED, 3LEAD, JEDEC VARIATION AB

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